

# **BC847BTT1G Datasheet**

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DiGi Electronics Part Number	BC847BTT1G-DG
Manufacturer	onsemi
Manufacturer Product Number	BC847BTT1G
Description	TRANS NPN 45V 0.1A SC75 SOT416
Detailed Description	Bipolar (BJT) Transistor NPN 45 V 100 mA 100MHz 2 25 mW Surface Mount SC-75, SOT-416

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Tel: +00 852-30501935

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC847BTT1G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	600mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
15nA (ICBO)	200 @ 2mA, 5V
Power - Max:	Frequency - Transition:
225 mW	100MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
SC-75, SOT-416	SC-75, SOT-416
Base Product Number:	
BC847	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	

# onsemi

# General Purpose Transistors

## **NPN Silicon**

# BC847ATT1, BC847BTT1, BC847CTT1

These transistors are designed for general purpose amplifier applications. They are housed in the SC-75/SOT-416 package which is designed for low power surface mount applications.

#### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free Packages are Available

#### MAXIMUM RATINGS (T<sub>A</sub> = 25 °C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	45	V
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current – Continuous	Ι <sub>C</sub>	100	mAdc

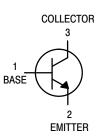
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) T <sub>A</sub> = 25 °C	P <sub>D</sub>	200	mW
Derated above 25 °C		1.6	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ hetaJA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) $T_{A} = 25 \ ^{\circ}C$	P <sub>D</sub>	300	mW
Derated above 25 °C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	400	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

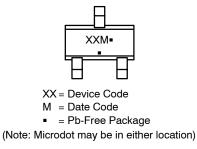
1. FR-4 @ min pad.

2. FR-4 @ 1.0 × 1.0 in pad.





#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 5 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 5.

## BC847ATT1, BC847BTT1, BC847CTT1

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C unless otherwise noted)

	Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				-	-	-
Collector - Emitter Breakdown $(I_C = 10 \text{ mA})$	Voltage BC847 Series	V <sub>(BR)CEO</sub>	45	_	-	V
Collector - Emitter Breakdown ( $I_C = 10 \ \mu A, \ V_{EB} = 0$ )	Voltage BC847 Series	V <sub>(BR)CES</sub>	50	_	_	V
Collector - Base Breakdown V ( $I_C = 10 \ \mu A$ )	oltage BC847 Series	V <sub>(BR)</sub> CBO	50	_	_	V
Emitter - Base Breakdown Vol (I <sub>E</sub> = 1.0 $\mu$ A)	tage BC847 Series	V <sub>(BR)EBO</sub>	6.0	_	_	V
Collector Cutoff Current	$(V_{CB} = 30 \text{ V})$ $(V_{CB} = 30 \text{ V}, \text{ T}_{\text{A}} = 150 ^{\circ}\text{C})$	I <sub>CBO</sub>	- -		15 5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I <sub>C</sub> = 10 $\mu$ A, V <sub>CE</sub> = 5.0 V)	BC847A BC847B BC847C	h <sub>FE</sub>	- - -	90 150 270	- - -	_
$(I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC847A BC847B BC847C		110 200 420	180 290 520	220 450 800	
Collector - Emitter Saturation	Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.5 mA) (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 5.0 mA)	V <sub>CE(sat)</sub>	-		0.25 0.6	V
Base - Emitter Saturation Volta	age ( $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ ) ( $I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$ )	V <sub>BE(sat)</sub>	-	0.7 0.9	_ _	V
Base - Emitter Voltage ( $I_C = 2$ . ( $I_C = 1$	0 mA, V <sub>CE</sub> = 5.0 V) 0 mA, V <sub>CE</sub> = 5.0 V)	V <sub>BE(on)</sub>	580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTI	ERISTICS	I				-
Current - Gain – Bandwidth Pr $(I_C$ = 10 mA, $V_{CE}$ = 5.0 Vdc, f		f <sub>T</sub>	100	_	_	MHz
Output Capacitance ( $V_{CB} = 1$	0 V, f = 1.0 MHz)	C <sub>obo</sub>	_	-	4.5	pF
Noise Figure ( $I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ Vdc},$	R <sub>S</sub> = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz)	NF	_	_	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

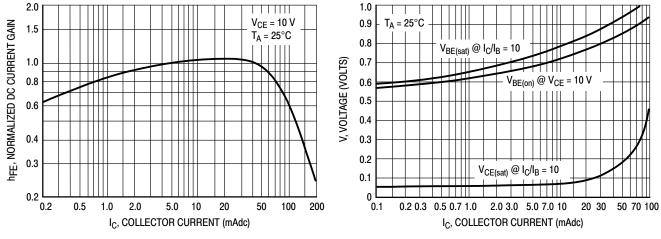




Figure 2. "Saturation" and "On" Voltages

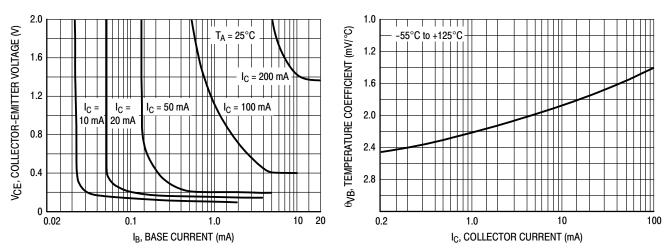


Figure 3. Collector Saturation Region

Figure 4. Base-Emitter Temperature Coefficient

BC847ATT1, BC847BTT1, BC847CTT1

BC847

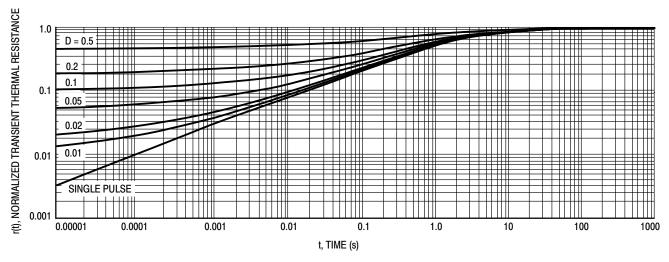
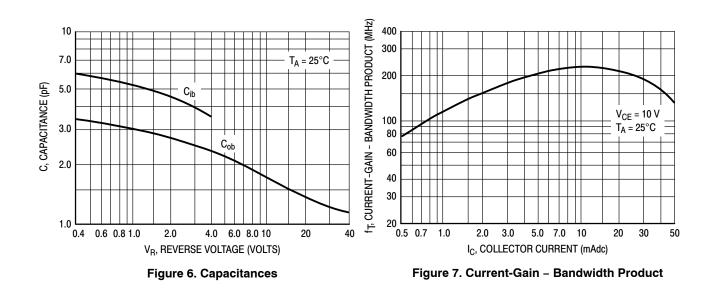


Figure 5. Normalized Thermal Response



#### BC847BTT1G onsemi TRANS NPN 45V 0.1A SC75 SOT416

### BC847ATT1, BC847BTT1, BC847CTT1

#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
BC847ATT1	1E	SC-75/SOT-416	3,000 / Tape & Reel
BC847BTT1G	1F	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel
NSVBC847BTT1G*	1F	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel

#### **DISCONTINUED** (Note 3)

BC847BTT1	1F	SC-75/SOT-416	3,000 / Tape & Reel
BC847CTT1G	1G	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

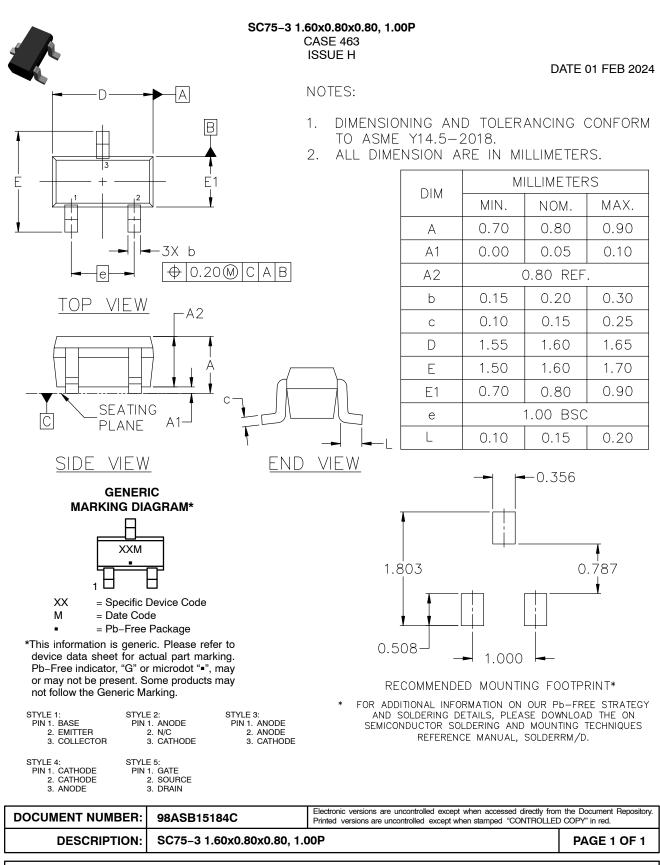
\*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

3. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.



## MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



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